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Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation, and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!


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## HiPerFAST ${ }^{\text {TM }}$ IGBT

## IXGH 24N60B

| Preliminary Data |  |  |  |
| :---: | :---: | :---: | :---: |
| Symbol | Test Conditions | Maximum | Ratings |
| $\mathrm{V}_{\text {CES }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | 600 | V |
| $\mathrm{V}_{\mathrm{cGR}}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C} ; \mathrm{R}_{\mathrm{GE}}=1 \mathrm{M} \Omega$ | 600 | V |
| $\mathrm{V}_{\text {GES }}$ | Continuous | $\pm 20$ | V |
| $\mathrm{V}_{\text {GEM }}$ | Transient | $\pm 30$ | V |
| $\mathrm{I}_{\mathrm{c} 25}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}$ | 48 | A |
| $\mathrm{I}_{\text {c90 }}$ | $\mathrm{T}_{\mathrm{c}}=90^{\circ} \mathrm{C}$ | 24 | A |
| $\mathrm{I}_{\text {cm }}$ | $\mathrm{T}_{\mathrm{c}}=25^{\circ} \mathrm{C}, 1 \mathrm{~ms}$ | 96 | A |
| $\begin{aligned} & \text { SSOA } \\ & \text { (RBSOA) } \end{aligned}$ | $\mathrm{V}_{\mathrm{GE}}=15 \mathrm{~V}, \mathrm{~T}_{\mathrm{VJ}}=125^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{G}}=22 \Omega$ <br> Clamped inductive load | $\mathrm{I}_{\mathrm{CM}}=48$ $@ 0.8 \mathrm{~V}_{\text {CES }}$ | A |
| $\mathrm{P}_{\mathrm{c}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 150 | W |
| $\mathrm{T}_{\mathrm{J}}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {JM }}$ |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| Maximum lead temperature for soldering 1.6 mm ( 0.062 in .) from case for 10 s |  | 300 | ${ }^{\circ} \mathrm{C}$ |
| $M_{\text {d }}$ | Mounting torque (M3) | 1.13/10 | Nm/lb.in. |
| Weight |  | 6 | g |


| Symbol | Test Conditions | Characteristic Values ( $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, unless otherwise specified) min. ${ }^{\text {typ. }}$ max. |  |  |
| :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \mathrm{BV}_{\mathrm{CES}} \\ & \mathbf{V}_{\mathrm{GE}(\mathrm{~h})} \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=250 \mu \mathrm{~A}, \mathrm{~V}_{G E}=0 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{C}}=250 \mu \mathrm{~A}, \mathrm{~V}_{\mathrm{CE}}=\mathrm{V}_{\mathrm{GE}} \end{aligned}$ | $\begin{array}{r} 600 \\ 2.5 \end{array}$ |  | 5.5 V |
| $\mathrm{I}_{\text {ces }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=0.8 \cdot \mathrm{~V}_{\mathrm{CES}} \\ & \mathrm{~V}_{\mathrm{GE}}=0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{J}}=125^{\circ} \mathrm{C} \end{aligned}$ |  | $\begin{array}{rl} 200 & \mu \mathrm{~A} \\ 1 & \mathrm{~mA} \end{array}$ |
| $\mathrm{I}_{\text {GES }}$ | $\mathrm{V}_{\mathrm{CE}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{GE}}= \pm 20 \mathrm{~V}$ |  |  | $\pm 100 \mathrm{nA}$ |
| $\mathrm{V}_{\text {CE(sat) }}$ | $\mathrm{I}_{\mathrm{C}} \quad=\mathrm{I}_{\text {C90 }}, \mathrm{V}_{\text {GE }}=15 \mathrm{~V}$ |  |  | 2.3 V |



TO-247 AD

$\mathrm{G}=$ Gate, $\quad \mathrm{C}=$ Collector, $E=$ Emitter,$\quad T A B=$ Collector

## Features

- International standard packages JEDEC TO-247 SMD surface mountable and JEDEC TO-247 AD
- High frequency IGBT
- High current handling capability
- 3rd generation $\mathrm{HDMOS}^{\text {TM }}$ process
- MOS Gate turn-on
- drive simplicity


## Applications

- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies


## Advantages

- High power density
- Switching speed for high frequency applications
- Easy to mount with 1 screw (insulated mounting screw hole)

Symbol

Characteristic Values ( $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, unless otherwise specified) min. typ. $^{\text {ty }}$ max.


Min. Recommended Footprint (Dimensions in inches and (mm))


IXYS reserves the right to change limits, test conditions, and dimensions.


Fig. 1. Saturation Voltage Characteristics


Fig. 3. Saturation Voltage Characteristics


Fig. 5. Admittance Curves


Fig. 2. Extended Output Characteristics


Fig. 4. Temperature Dependence of $\mathrm{V}_{\mathrm{CE}(\text { sat })}$


Fig. 6. Temperature Dependence of $B V_{D S S} \& V_{G E(\mathrm{~h})}$


Fig. 7. Dependence of tfi and $E_{\text {off }}$ on $I_{C}$.


Fig. 9. Gate Charge


Fig. 8. Dependence of tfi and $E_{\text {OFF }}$ on $R_{G}$.


Fig. 10. Turn-off Safe Operating Area


Fig. 11. Transient Thermal Resistance
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